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国際調査報告書

2文字コード及び他の略語については、 定期発行される 各PCTガゼットの巻頭に掲載されている「コードと略語 のガイダンスノート」を参照。

(54) Title: PROCESS FOR PREVENTING DEVELOPMENT DEFECT AND COMPOSITION FOR USE IN THE SAME

(54) 発明の名称: 現像欠陥防止プロセスおよびそれに用いる組成物

(57) Abstract: A composition for preventing development defects which contains (1) a salt of a C4-15 perfluoroalkylcarboxylic acid, C4-10 perfluoroalkylsulfonic acid, or perfluoroadipic acid with ammonium, a tetraalkylammonium, or a C1-4 alkanolamine or (2) a salt of an inorganic acid with a quaternary fluoroalkylammonium salt, and in which the acid/base equivalent ratio is from 1/1 to 1/3. This composition is applied to a positive-acting chemical amplification type photoresist film formed on a substrate having a diameter as large as 8 inches or more. Before and/or after application of the composition for preventing development defects, the chemical amplification type photoresist film is baked. This photoresist film is subjected to exposure and post-exposure baking and is then developed. Thus, the decrease in photoresist film thickness through development can be larger by 100 to 600 Å than that in the case where the composition for preventing development defects is not applied. Development defects on substrates having a diameter as large as 8 inches or more are diminished, and resist patterns having a satisfactory sectional shape free from T-top or the like are formed.

(57) 要約: 8インチ以上の大口径基板上に形成されたポジ型化学増幅型フォトレジスト膜上に、酸と塩基の当量 比が1:1~1:3として形成された(1) $C_4 \sim C_{15}$ のパーフルオロアルキルカルボン酸、 $C_4 \sim C_{10}$ のパーフ 😽 ルオロアルキルスルホン酸あるいはパーフルオロアジピン酸のアンモニウム塩、テトラアルキルアンモニウム塩ま たはC<sub>1</sub>~C<sub>4</sub>のアルカノールアミン塩、または(2)無機酸のフッ素化アルキル4級アンモニウム塩を含む現像欠 陥防止用組成物を塗布し、前記現像欠陥防止用組成物を塗布する前および/または塗布後に化学増幅型フォトレジ ペラスト膜をベークした後、露光、露光後ベークを行い、現像する。これにより、現像欠陥防止用組成物を塗布しない 場合に比べ現像処理後のフォトレジストの膜厚の減少量が、更に100Å~600Å大きくされ、8インチ以上の 大口径基板における現像欠陥が低減されるとともに、T-トップ形状などのない良好な断面形状のレジストパター ンが形成される。

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•		INTERNATIO	L SEAL	RCH REPORT		PTO.	TWB0360700
A.	CLASSIFIC Int.Cl7	ATION OF SUBJECT G03F7/38,	T MATTER 7/11, H		Rec'd PCT	10,00	

According to International Patent Classification (IPC) or to both national classification and IPC

#### FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols) Int.Cl<sup>7</sup> G03F7/38, 7/11, H01L21/027

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched 1994-2003 Toroku Jitsuyo Shinan Koho 1922-1996 Jitsuyo Shinan Koho Jitsuyo Shinan Toroku Koho 1996-2003 1971-2003 Kokai Jitsuyo Shinan Koho

Electronic data base consulted during the international search (name of data base and, where practicable, search terms used)

### C. DOCUMENTS CONSIDERED TO BE RELEVANT

Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X ·	WO 02/29493 A1 (Clariant International Ltd.), 03 January, 2002 (03.01.02), Full text & JP 2002-6514 A & EP 1306726 A1	1,2
х	JP 2001-133984 A (Shin-Etsu Chemical Co., Ltd.), 18 May, 2001 (18.05.01), Full text (Family: none)	1,2
х	JP 2002-148821 A (Shin-Etsu Chemical Co., Ltd.), 22 May, 2002 (22.05.02), Full text (Family: none)	1,2

Further documents are listed in the continuation of Box C.	See patent family annex.
* Special categories of cited documents:  "A" document defining the general state of the art which is not considered to be of particular relevance  "E" earlier document but published on or after the international filing date  "L" document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified)  "O" document referring to an oral disclosure, use, exhibition or other means  "P" document published prior to the international filing date but later than the priority date claimed	"T" later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone "Y" document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art document member of the same patent family
Date of the actual completion of the international search 02 September, 2003 (02.09.03)	Date of mailing of the international search report  16 September, 2003 (16.09.03)
Name and mailing address of the ISA/ Japanese Patent Office	Authorized officer
Facsimile No.	Telephone No.

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